

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application	)	<u>PATENT APPLICATION</u>
	)	
Inventor:	Jian Chen, et al.	)
	)	Art Unit: 2824
Application No.:	10/765,963	)
	)	Examiner: Tran, Andrew Q.
Filed Date:	January 26, 2004	)
	)	<b>Customer No.: 64948</b>
Title: METHOD OF READING NAND MEMORY)	)	
TO COMPENSATE FOR COUPLING BETWEEN)	)	
STORAGE ELEMENTS	)	
	)	

RESPONSE A TO OFFICE ACTION UNDER 37 C.F.R. § 1.111

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

This RESPONSE A is in reply to the Office Action mailed September 27, 2006.

AMENDMENTS TO THE CLAIMS are reflected in the listing of claims which begin on page 2 of this Response.

AMENDMENTS TO THE ABSTRACT are reflected in the listing of claims which begin on page 7 of this Response.

AMENDMENTS TO THE DRAWINGS are reflected in the listing of claims which begin on page 8 of this Response.

REMARKS begin on Page 9 of this Response.